MOSFETs Silicon N-Channel MOS (U-MOSVII-H)

TPC8065-H

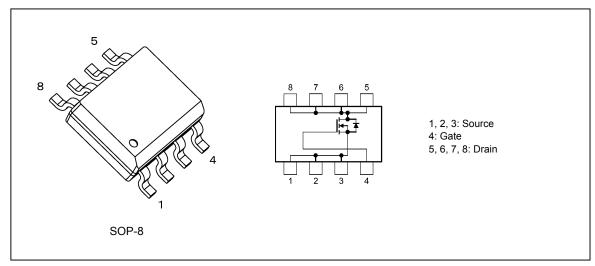
1. Applications

- High-Efficiency DC-DC Converters
- Notebook PCs
- Mobile Handsets

2. Features

- (1) Small, thin package
- (2) High-speed switching
- (3) Small gate charge: $Q_{SW} = 4.3 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 11.9 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 4.5 \text{ V})$
- (5) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 30 \ V)$
- (6) Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_D = 0.2 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

Characterist	Symbol	Rating	Unit		
Drain-source voltage			V _{DSS}	30	V
Gate-source voltage			V _{GSS}	-20/+20	
Drain current (DC)		(Note 1)	Ι _D	13	А
Drain current (pulsed)		(Note 1)	I _{DP}	52	
Power dissipation	(t = 10 s)	(Note 2)	PD	1.9	W
Power dissipation	(t = 10 s)	(Note 3)	PD	1.0	W
Single-pulse avalanche energy		(Note 4)	E _{AS}	43	mJ
Avalanche current			I _{AR}	13	А
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

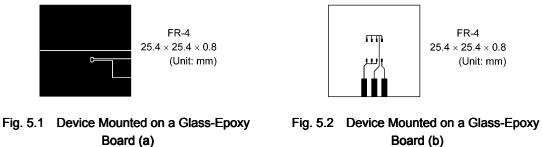
Characteristic	S		Symbol	Max	Unit
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 2)	R _{th(ch-a)}	65.7	°C/W
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 3)	R _{th(ch-a)}	125	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: V_{DD} = 24 V, T_{ch} = 25°C (initial), L = 0.2 mH, R_G = 1.2 Ω , I_{AR} = 13 A



Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

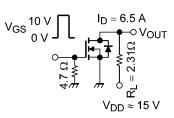
6. Electrical Characteristics

6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	—	_	±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	30	_	_	V
	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	15	_	_	
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.2 mA	1.3	_	2.3	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 4.5 V, I _D = 6.5 A	_	11.9	14.7	mΩ
		V _{GS} = 10 V, I _D = 6.5 A	_	9.6	11.6	

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz	_	1350	_	pF
Reverse transfer capacitance	C _{rss}		_	63	_	
Output capacitance	C _{oss}		_	240	_	
Gate resistance	rg	V_{DS} = 10 V, V_{GS} = 0 V, f = 5 MHz	1.0	1.4	2.1	Ω
Switching time (rise time)	tr	See Figure 6.2.1.	_	2.1	_	ns
Switching time (turn-on time)	t _{on}			8.0	_	
Switching time (fall time)	t _f]	_	2.4	_	1
Switching time (turn-off time)	t _{off}]	_	19	—	1



Duty \leq 1%, $t_W =$ 10 μs

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Qg	$V_{DD} \approx 24 \text{ V}, \text{ V}_{GS} \text{ = } 10 \text{ V}, \text{ I}_{D} \text{ = } 13 \text{ A}$	_	20	_	nC
gate-drain)		$V_{DD} \approx 24 \text{ V}, \text{ V}_{GS} = 5 \text{ V}, \text{ I}_{D} = 13 \text{ A}$	_	9.9	_	
Gate-source charge 1	Q _{gs1}	$V_{DD} \approx 24 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 13 \text{ A}$	_	4.4	—	
Gate-drain charge	Q _{gd}		_	2.1	_	
Gate switch charge	Q _{SW}		_	4.3	_	

6.4. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Pulsed reverse drain current (N	Note 5)	I _{DRP}	—			52	А
Diode forward voltage		V _{DSF}	I _{DR} = 13 A, V _{GS} = 0 V	_	_	-1.2	V

Note 5: Ensure that the channel temperature does not exceed 150°C.

7. Marking (Note)

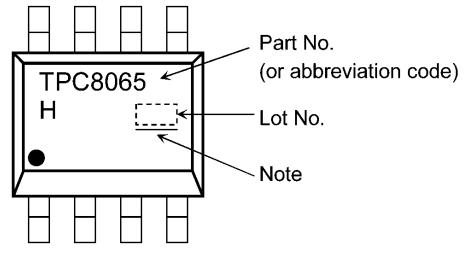
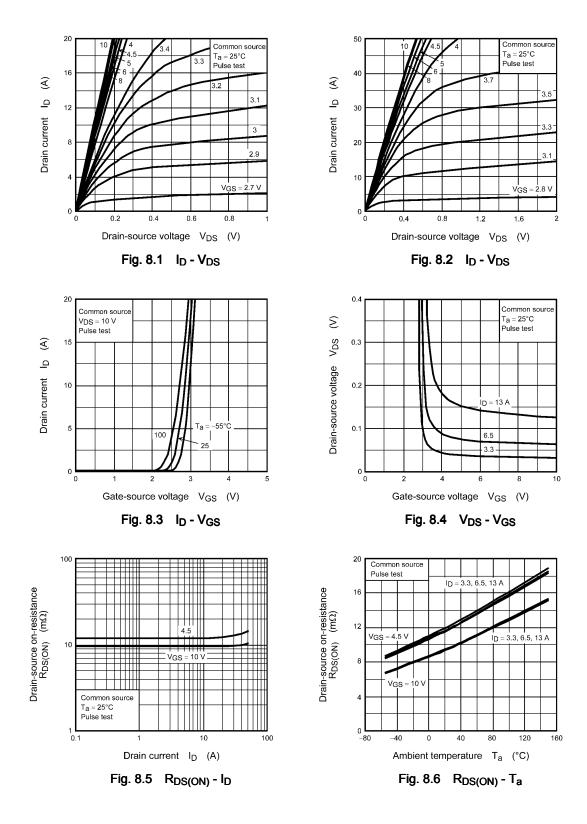


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)



2.5

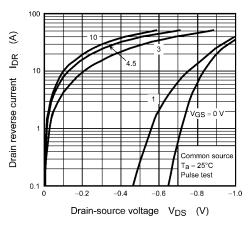
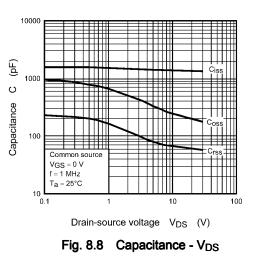


Fig. 8.7 IDR - VDS



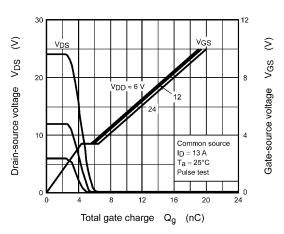
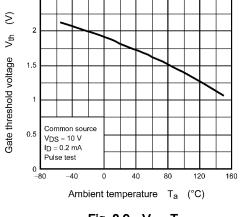
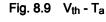
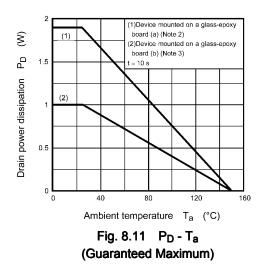


Fig. 8.10 Dynamic Input/Output Characteristics





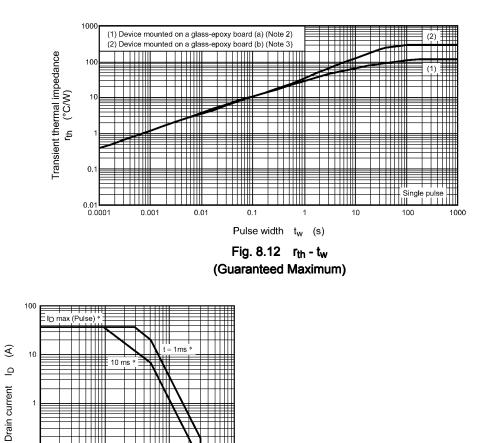


0.1

0.01 L 0.1

* Single pulse $T_a = 25^{\circ}C$ Curves must be derated linearly with increase in temperature.

1





Drain-source voltage V_{DS} (V)

VDSS ma

100

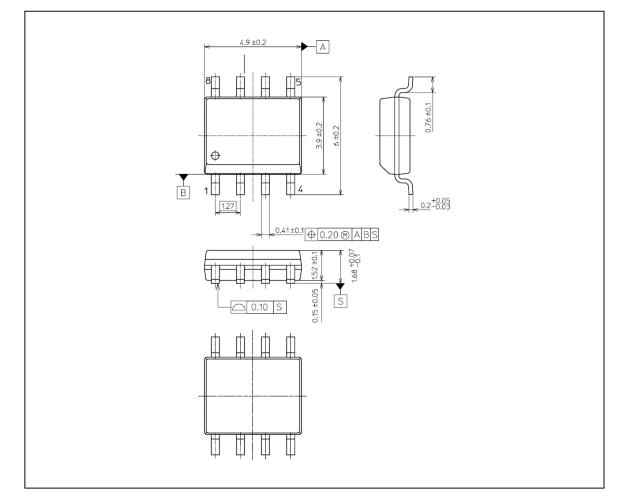
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Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

TPC8065-H

Unit: mm



Weight: 0.085 g (typ.)

Package Name(s)
TOSHIBA: 2-5R1S
Nickname: SOP-8

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